

New Application
Inv: Tohru OZAKI, et al.
Preliminary Amendment
Oblon Docket No.: 240324US-2 TTC DIV

DOCKET NO: 240324US-2 TTC DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
TOHRU OZAKI, ET AL. : ATTN: APPLICATION DIVISION
SERIAL NO: NEW APPLICATION :
FILED: HEREWITH :
FOR: SEMICONDUCTOR MEMORY :
DEVICE AND METHOD OF :
FABRICATING THE SAME :

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to examination on the merits, please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Remarks/Arguments begin on page 5 of this paper.